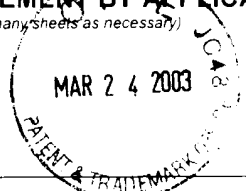


Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary) 	Complete if Known	
	Application Number	09/883795
	Filing Date	June 18, 2001
	First Named Inventor	Forbes, Leonard
	Group Art Unit	2814
	Examiner Name	Theresa T. Doan
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EXAMINER

L. Aron

DATE CONSIDERED

04/11/03